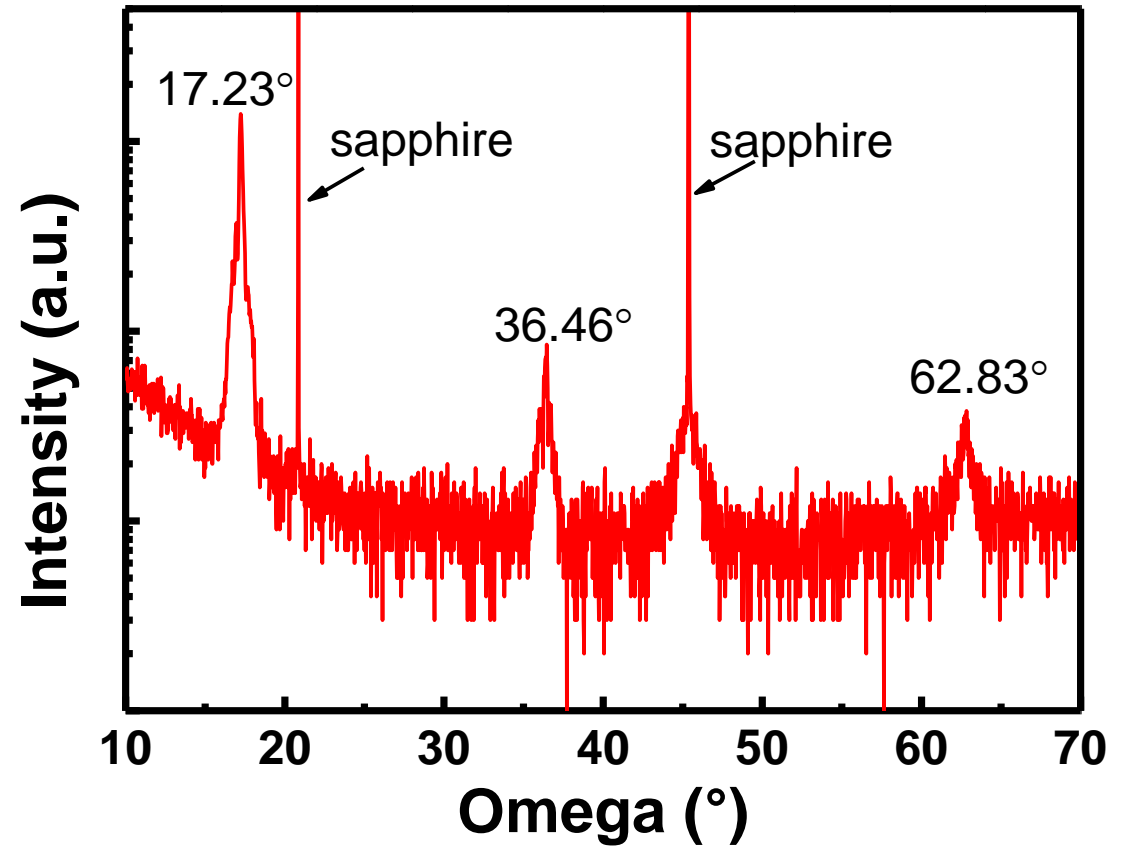


HR-TEM image of ~20 nm GaN grown at 350 °C on sapphire (0001) substrate. Inset image shows the as-grown GaN displays a single hexagonal (002) phase.



ω -2 θ scan of the same sample.